

补充材料 (2022 *Acta Phys. Sin.* 71 237302)

# Improvement of thermoelectric performance of SnTe-based solid solution by entropy engineering technology\*

Li Meng-Rong<sup>1)2)</sup> Ying Peng-Zhan<sup>2)</sup> Li Xie<sup>1)</sup> Cui Jiao-Lin<sup>1)†</sup>

1) (School of Materials Science and Chemical Engineering, Ningbo University of Technology, Ningbo 315211, China)

2) (School of Materials Science and Engineering, China University of Mining and Technology, Xuzhou 221116, China)

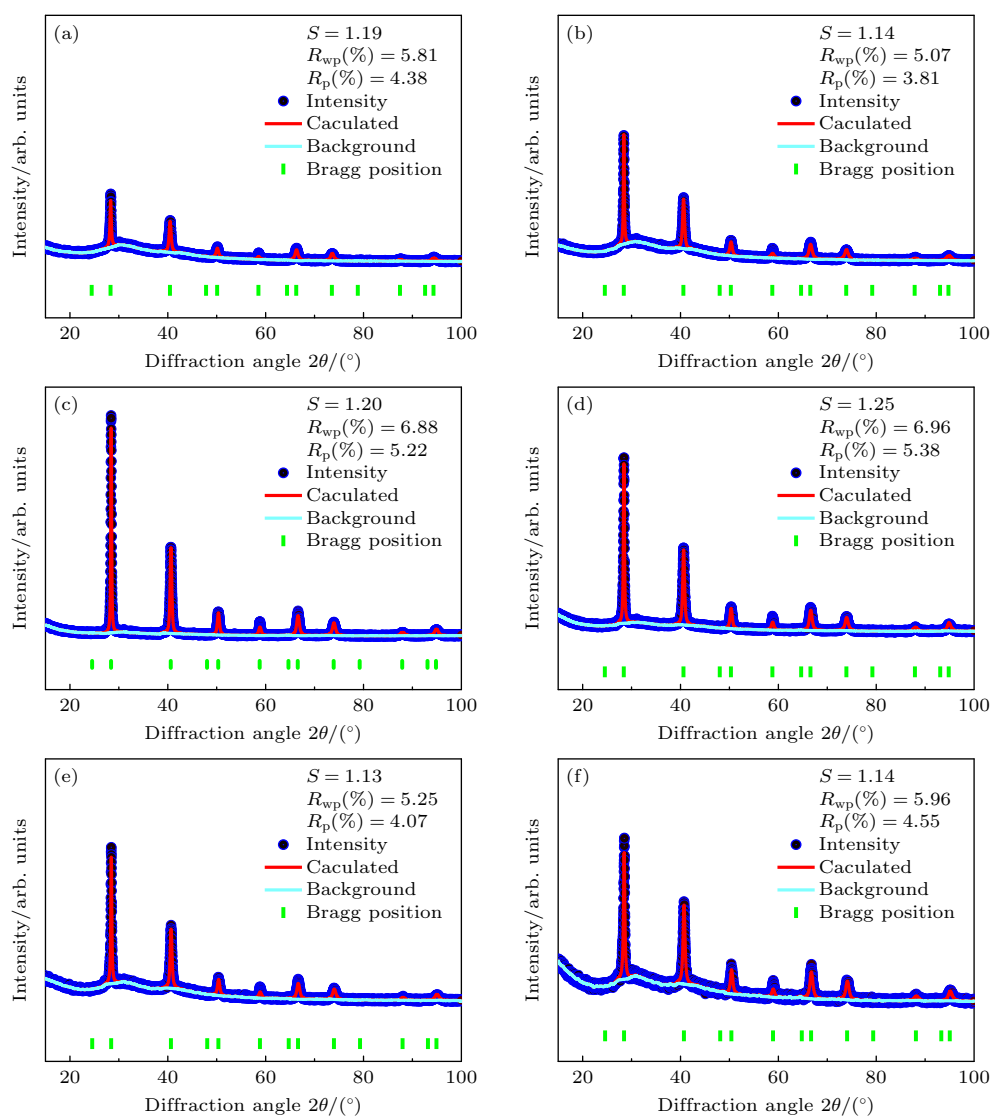


Fig. S1. XRD refinement patterns of different kinds of materials: (a)  $\text{Sn}_{0.95}\text{Ge}_{0.05}\text{Te}$ ; (b)  $(\text{Sn}_{0.95}\text{Ge}_{0.05}\text{Te})_{0.95}(\text{Ag}_2\text{Se})_{0.05}$ ; (c)  $(\text{Sn}_{0.925}\text{Ge}_{0.05}\text{Bi}_{0.025}\text{Te})_{0.95}(\text{Ag}_2\text{Se})_{0.05}$ ; (d)  $(\text{Sn}_{0.9}\text{Ge}_{0.05}\text{Bi}_{0.05}\text{Te})_{0.95}(\text{Ag}_2\text{Se})_{0.05}$ ; (e)  $(\text{Sn}_{0.875}\text{Ge}_{0.05}\text{Bi}_{0.075}\text{Te})_{0.95}(\text{Ag}_2\text{Se})_{0.05}$ ; (f)  $(\text{Sn}_{0.85}\text{Ge}_{0.05}\text{Bi}_{0.1}\text{Te})_{0.95}(\text{Ag}_2\text{Se})_{0.05}$ .

\* 国家自然科学基金 (批准号: 51671109) 资助的课题.

† Corresponding author. E-mail: [cuijiaolin@163.com](mailto:cuijiaolin@163.com)

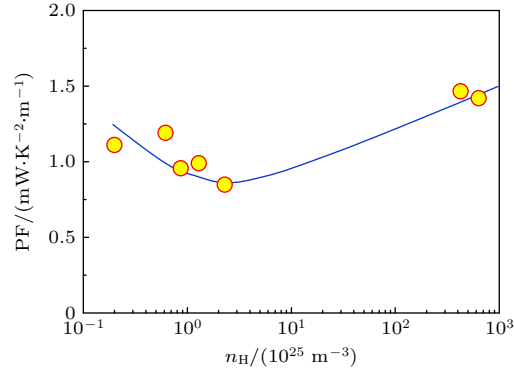


Fig. S2 Power factors (PF) versus Hall carrier concentration ( $n_H$ ) at room temperature for samples of  $(\text{Sn}_{0.95-x}\text{Ge}_{0.05}\text{Bi}_x\text{Te})_{0.95}(\text{Ag}_2\text{Se})_{0.05}$  ( $x=0, 0.025, 0.05, 0.075, 0.1$ ).

**Table S1.** XRD-refined related structural parameters and crystallographic data.

Compositions	$\text{Sn}_{0.95}\text{Ge}_{0.05}\text{Te}$	$x = 0$	$x = 0.025$	$x = 0.05$	$x = 0.075$	$x = 0.1$
Space group	<i>Fm-3m</i>	<i>Fm-3m</i>	<i>Fm-3m</i>	<i>Fm-3m</i>	<i>Fm-3m</i>	<i>Fm-3m</i>
$Z$	4	4	4	4	4	4
$a/\text{\AA}$	6.3042	6.2806	6.2778	6.2779	6.2736	6.2668
$V/\text{\AA}^3$	250.55	247.73	247.41	247.45	246.89	246.11
$R_p/\%$	4.38	3.81	5.22	5.38	4.07	4.55
$R_{wp}/\%$	5.81	5.07	6.88	6.96	5.25	5.96
GOF	1.19	1.14	1.20	1.25	1.13	1.14

**Table S2.** Atomic coordinates, atomic occupations and Wyckoff positions for different samples.

Compositions	Atom	Site	$x$	$y$	$z$	$B_{\text{iso}}$	Occupancy
$\text{Sn}_{0.95}\text{Ge}_{0.05}\text{Te}$	Sn1	4a	0	0	0	0.0012	0.95
	Ge1	4a	0	0	0	0.0012	0.05
	Te1	4b	1/2	1/2	1/2	0.0039	1
$x = 0$	Sn1	4a	0	0	0	0.0089	0.9025
	Ge1	4a	0	0	0	0.0026	0.0475
	Ag1	4a	0	0	0	0.0026	0.05
	Te1	4b	1/2	1/2	1/2	0.0092	0.95
	Se1	4b	1/2	1/2	1/2	0.0102	0.05
$x = 0.025$	Sn1	4a	0	0	0	0.0106	0.87875
	Ge1	4a	0	0	0	0.0031	0.0475
	Ag1	4a	0	0	0	0.0031	0.05
	Bi1	4a	0	0	0	0.0100	0.02375
	Te1	4b	1/2	1/2	1/2	0.0111	0.95
	Se1	4b	1/2	1/2	1/2	0.0124	0.05
$x = 0.05$	Sn1	4a	0	0	0	0.0054	0.855
	Ge1	4a	0	0	0	0.0037	0.0475
	Ag1	4a	0	0	0	0.0037	0.05
	Bi1	4a	0	0	0	0.0114	0.0475
	Te1	4b	1/2	1/2	1/2	0.0049	0.95
	Se1	4b	1/2	1/2	1/2	0.0142	0.05
$x = 0.075$	Sn1	4a	0	0	0	0.0032	0.83125
	Ge1	4a	0	0	0	0.0050	0.0475
	Ag1	4a	0	0	0	0.0049	0.05
	Bi1	4a	0	0	0	0.0131	0.07125
	Te1	4b	1/2	1/2	1/2	0.0028	0.95
	Se1	4b	1/2	1/2	1/2	0.0180	0.05
$x = 0.1$	Sn1	4a	0	0	0	0.0009	0.8075
	Ge1	4a	0	0	0	0.0062	0.0475
	Ag1	4a	0	0	0	0.0059	0.05
	Bi1	4a	0	0	0	0.0050	0.095
	Te1	4b	1/2	1/2	1/2	0.0008	0.95
	Se1	4b	1/2	1/2	1/2	0.0174	0.05